

Features

- No Direction-Control Signal Needed
- Maximum Data Rates
 - 110 Mbps (Push Pull)
 - 1.2 Mbps (Open Drain)
- 1.1 V to 1.95 V on A Port and 1.65 V to 5.5 V on B Port (VCCA ≤ VCCB)
- No Power-Supply Sequencing Required –
 Either VCCA or VCCB Can Be Ramped First
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection
 - 8000 V Human Body Model
 - 1000 V Charged-Device Model

Applications

- Handsets
- Smartphones
- Tablets
- Desktop PCs

Description

This device is a 8-bit non-inverting level translator which uses two separate configurable power-supply rails. The A port tracks the VCCA pin supply voltage. The VCCA pin accepts any supply voltage between 1.1 V and 1.95 V. The B port tracks the VCCB pin supply voltage. The VCCB pin accepts any supply voltage between 1.65 V and 5.5 V. Two input supply pins allows for low Voltage bidirectional translation between any of the 1.5 V, 1.8 V, 2.5 V, 3.3 V, and 5 V voltage nodes.

When the output-enable (OE) input is low, all outputs are placed in the high-impedance (Hi-Z) state.

To ensure the Hi-Z state during power-up or power-down periods, tie OE to GND through a pull-down resistor. The minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Information

| Part Number | Package | Description |
|-------------|----------|-----------------|
| RS7LS108LE | TSSOP-20 | 6.5 mm × 6.4 mm |
| RS7LS108ZCE | QFN-20 | 3.5 mm × 4.5 mm |

Notes: E = Pb-free and Green



Block Diagram

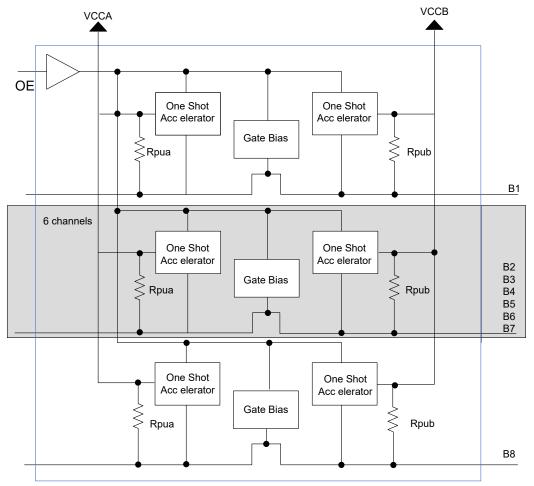
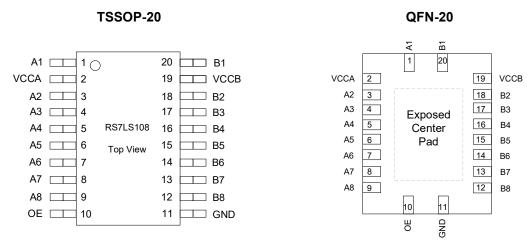


Figure 1. RS7LS108 block diagram



Pin Configuration



| Pin Name | TSSOP-20 | QFN-20 | Туре | Description |
|----------|----------|--------|-------|-----------------------------------------------------------------------------------------------------|
| A1 | 1 | 1 | I/O | Input/output 1. Referenced to VCCA |
| A2 | 3 | 3 | I/O | Input/output 2. Referenced to VCCA |
| A3 | 4 | 4 | I/O | Input/output 3. Referenced to VCCA |
| A4 | 5 | 5 | I/O | Input/output 4. Referenced to VCCA |
| A5 | 6 | 6 | I/O | Input/output 5. Referenced to VCCA |
| A6 | 7 | 7 | I/O | Input/output 6. Referenced to VCCA |
| A7 | 8 | 8 | I/O | Input/output 7. Referenced to VCCA |
| A8 | 9 | 9 | I/O | Input/output 8. Referenced to VCCA |
| B1 | 20 | 20 | I/O | Input/output 1. Referenced to VCCB |
| B2 | 18 | 18 | I/O | Input/output 2. Referenced to VCCB |
| В3 | 17 | 17 | I/O | Input/output 3. Referenced to VCCB |
| B4 | 16 | 16 | I/O | Input/output 4. Referenced to VCCB |
| B5 | 15 | 15 | I/O | Input/output 5. Referenced to VCCB |
| B6 | 14 | 14 | I/O | Input/output 6. Referenced to VCCB |
| B7 | 13 | 13 | I/O | Input/output 7. Referenced to VCCB |
| B8 | 12 | 12 | I/O | Input/output 8. Referenced to VCCB |
| GND | 11 | 11 | _ | Ground |
| OE | 10 | 10 | Input | Tri-state output-mode enable. Pull OE low to place all outputs in 3-state mode. Referenced to VCCA. |
| VCCA | 2 | 2 | Power | A-port supply voltage. 1.1 V ≤ VCCA ≤ 1.95 V, VCCA ≤ VCCB. |
| VCCB | 19 | 19 | Power | B-port supply voltage. 1.65 V ≤ VCCB ≤ 5.5 V. |



Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)

| Parameter | | MIN | MAX | UNIT | |
|------------------------------------------------------------|--------|------|------------|----------|--|
| Supply voltage, VCCA | | -0.5 | 2.5 | V | |
| Supply voltage, VCCB | | -0.5 | 6.5 | V | |
| Input voltage VI | A port | -0.5 | 2.5 | V | |
| Input voltage, VI | B port | -0.5 | 6.5 | V | |
| Voltage applied to any output | A port | -0.5 | 2.5 | V | |
| in the high-impedance or power-off state, VO | B port | -0.5 | 6.5 | v | |
| Voltage applied to any output in the high or law state. VO | A port | -0.5 | VCCA + 0.5 | V | |
| Voltage applied to any output in the high or low state, VO | B port | -0.5 | VCCB + 0.5 | V | |
| Input clamp current, IIK | VI < 0 | - | mA | | |
| Output clamp current, IOK | VO < 0 | - | -50 | mA | |
| Continuous output current, IO | | -50 | 50 | mA | |
| Continuous current through VCCA, VCCB, or GND | -100 | 100 | mA | | |
| Junction temperature, TJ | | °C | | | |
| Storage temperature, Tstg | | -65 | 150 | °C | |

Note: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Condtions is not implied.

Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | | Parameter | | MIN | MAX | UNIT |
|-------|--------------------------------|--------------------------|------------------------|------------------------|-------------|-------------|------|
| VCCA | | | Supply voltage | | 1.1 | 1.95 | V |
| VCCB | | | Supply voltage | | 1.65 | 5.5 | V |
| | High-level | A-Port I/Os | VCCA (V) = 1.1 to 1.95 | VCCB (V) = 1.65 to 5.5 | VCCI - 0.2 | VCCI | V |
| VIH | input | B-Port I/Os | VCCA (V) = 1.1 to 1.95 | VCCB (V) = 1.65 to 5.5 | VCCI - 0.4 | VCCI | V |
| | voltage | OE | VCCA (V) = 1.1 to 1.95 | VCCB (V) = 1.65 to 5.5 | VCCA × 0.65 | VCCA | V |
| | Low-level input voltage | A-Port I/Os | VCCA (V) = 1.1 to 1.95 | VCCB (V) = 1.65 to 5.5 | 0 | 0.15 | V |
| VIL | | B-Port I/Os | VCCA (V) = 1.1 to 1.95 | VCCB (V) = 1.65 to 5.5 | 0 | 0.15 | V |
| V.E | | OE | VCCA (V) = 1.1 to 1.95 | VCCB (V) = 1.65 to 5.5 | 0 | VCCA × 0.35 | V |
| | Input | A-Port I/Os Push-pull | VCCA (V) = 1.1 to 1.95 | VCCB (V) = 1.65 to 5.5 | 10 | | ns/V |
| Δt/Δν | transition rise or fall | B-Port I/Os Push-pull | VCCA (V) = 1.1 to 1.95 | VCCB (V) = 1.65 to 5.5 | 10 | | ns/V |
| | rate | Control input | VCCA (V) = 1.1 to 1.95 | VCCB (V) = 1.65 to 5.5 | 1 | 0 | ns/V |
| TA | Operating free-air temperature | | | | -40 | 125 | °C |



Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

| | • | ating free-air temperature | | | TA = | 25°C | | LINUT |
|--------|-------------------------------------------------------|-------------------------------------|-------------|-------------|-------------|------|------------|----------|
| PAF | RAMETER | TEST CONDITIONS | VCCA (V) | VCCB (V) | MIN | TYP | MAX | UNIT |
| VOHA | Port A output high voltage | IOH = -20 μA VIB ≥ VCCB - 0.4 V | 1.1 | 1.65 to 5.5 | VCCA × 0.67 | | | V |
| | | IOL = 180 μA, VIB ≤ 0.15 V | 1.1 | 1.65 to 5.5 | | | 0.4 | |
| VOLA | Port A output low voltage | IOL = 220 μA, VIB ≤ 0.15 V | 1.65 | 1.65 to 5.5 | | | 0.4 | |
| | | IOL = 300 μA, VIB ≤ 0.15 V | 1.95 | 1.65 to 5.5 | | | 0.4 | ٧ |
| VOHB | Port B output high voltage | IOH = −20 μA, VIA ≥ VCCA − 0.2 V | 1.1 | 1.65 to 5.5 | VCCB × 0.67 | | | V |
| | | IOL = 220 μA, VIA ≤ 0.15 V | 1.1 to 1.95 | 1.65 | | | 0.4 | |
| V01.5 | Port B output | IOL = 300 μA, VIA ≤ 0.15 V | 1.1 to 1.95 | 2.3 | | | 0.4 | |
| | low voltage | IOL = 400 μA, VIA ≤ 0.15 V | 1.1 to 1.95 | 3 | | | 0.55 | ٧ |
| | | IOL = 620 μA, VIA ≤ 0.15 V | 1.1 to 1.95 | 4.5 | | | 0.55 | |
| li | Input leakage current | OE: VI = VCCI or GND | 1.1 | 1.65 to 5.5 | | | <u>±</u> 1 | μA |
| IOZ | High- impedance state output current | A or B port | 1.1 | 1.65 to 5.5 | | | ±1 | μΑ |
| | | | 1.1 | 1.65 to 5.5 | | 1 | | |
| ICCA | VCCA supply | VI = VO = Open, | 1.2 to 1.95 | 2.3 to 5.5 | | 1 | | |
| ICCA | current | | 1.95 | 0 | | | 1 | μA |
| | | | 0 | 5.5 | | | -1 | |
| | | | 1.1 | 1.65 to 5.5 | | 2 | | |
| 1000 | VCCB supply | VI = VO = Open, | 1.2 to 1.95 | 2.3 to 5.5 | | 2 | | |
| ICCB | current | IO = 0 | 1.95 | 0 | | | -1 | μA |
| | | | 0 | 5.5 | | | 1 | |
| ICCA + | Combined | VI = VCCI or GND, IO = | 1.1 | 2.3 to 5.5 | | 3 | | μA |
| ICCB | supply current | 0 | 1.2 to 1.95 | 2.3 to 5.5 | | 3 | | |
| ICCZA | High- impedance state VCCA supply current | VI = VO = Open, IO = 0, OE = GND | 1.1 | 1.65 to 5.5 | | 0.05 | | μА |
| ICCZB | High- impedance state VCCB supply current | VI = VO = Open, IO = 0, OE = GND | 1.1 | 1.65 to 5.5 | | 2 | | μΑ |

5

VCCI is the VCC associated with the data input port. VCCO is the VCC associated with the output port.

VCCA must be less than or equal to VCCB, and VCCA must not exceed 1.95V.



AC Electrical characteristics

VCCA = 1.2 V, over recommended operating free-air temperature range, (unless otherwise noted)

| DAF | DAMETER | TEST CONDITIONS | | VCCB | = 1.8 V | VCCB | = 2.5 V | VCCB | = 3.3 V | VCCB = 5 V | | UNIT |
|----------------------|-------------------------|---------------------------------------------------|-----------------------|------|---------|------|---------|------|---------|------------|-----|--------|
| PAI | RAMETER | IESI C | SNOTTIONS | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | UNII |
| tPHL | Propagation delay time | | Push-pull driving | | 11 | | 9.2 | | 8.6 | | 8.6 | |
| (high-to-low output) | A-to-B | Open-drain driving | | 14.4 | | 12.8 | | 12.2 | | 12 | no | |
| tPLH | Propagation delay time | | Push-pull driving | | 12 | | 10 | | 9.8 | | 9.7 | ns |
| UF LIT | (low-to-high output) | A-to-B | Open-drain driving | | 720 | | 554 | | 473 | | 384 | |
| tPHL | Propagation delay time | | Push-pull driving | | 12.7 | | 11.1 | | 11 | | 12 | |
| IFFIL | (high-to-low output) | B-to-A | Open-drain driving | | 13.2 | | 9.6 | | 8.5 | | 7.5 | |
| tPLH | Propagation delay time | | Push-pull driving | | 9.5 | | 6.2 | | 5.1 | | 1.6 | no |
| u Lii | (low-to-high output) | B-to-A | Open-drain driving | | 745 | | 603 | | 519 | | 407 | ns |
| ten | Enable time | OE-to-A or B | Push-pull driving | | 600 | | 400 | | 400 | | 400 | |
| tdis | Disable time | OE-to-A or B | Push-pull driving | | 400 | | 400 | | 400 | | 400 | |
| trA | Input rise time | A-port | Push-pull driving | | 13.1 | | 9.8 | | 9 | | 8.3 | ns |
| u/A | | rise time | Open-drain driving | | 982 | | 716 | | 592 | | 481 | 113 |
| trB | Input rise | B-port | Push-pull driving | | 11.4 | | 7.4 | | 4.7 | | 2.6 | ns |
| | time | rise time | Open-drain driving | | 1020 | | 756 | | 653 | | 370 | 110 |
| tfA | Input fall time | A-port fall time | Push-pull driving | | 9.9 | | 7.7 | | 6.8 | | 6 | |
| | unie | iali liille | Open-drain driving | | 10 | | 7.9 | | 7 | | 6.2 | |
| tfB | Input fall | B-port | Push-pull driving | | 8.7 | | 5.5 | | 3.8 | | 3.1 | ns |
| | time | fall time | Open-drain driving | | 11.5 | | 8.6 | | 9.6 | | 7.7 | |
| tSK(O) | Skew (time), output | Channel- to- channel skew | Push-pull driving | | 1 | | 1 | | 1 | | 1 | ns |
| Mavim | num data rate | m data rate A or B Push-pu driving Open-dra | Push-pull driving | 40 | | 60 | | 70 | | 70 | | Mbps |
| iviaxilli | iuiii uala iale | | Open-drain driving | 0.8 | | 0.8 | | 1 | | 1 | | INIDHS |



VCCA = 1.5 V

over recommended operating free-air temperature range, (unless otherwise noted)

| | | TEST CONDITIONS | | VCCB | = 1.8 V | VCCE | 3 = 2.5 V | VCCE | 3 = 3.3 V | VCCB = 5 V | | |
|-----------|---------------------------|------------------------------------|-----------------------|------|---------|------|-----------|------|-----------|------------|------|-----------|
| PAR | RAMETER | | | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | UNIT |
| tPHL | Propagation delay time | A-to-B | Push-pull driving | | 8.2 | | 6.4 | | 5.7 | | 5.6 | ns |
| u IIL | (high-to-low output) | 710-0 | Open-drain driving | | 11.4 | | 9.9 | | 9.3 | | 8.9 | 113 |
| tPLH | Propagation delay time | A-to-B | Push-pull driving | | 9 | | 2.1 | | 6.5 | | 6.3 | ns |
| | (low-to-high output) | A-10-D | Open-drain driving | | 729 | | 584 | | 466 | | 346 | 110 |
| tPHL | Propagation delay time | B-to-A | Push-pull driving | | 9.8 | | 8 | | 7.4 | | 7 | ns |
| u IIL | (high-to-low output) | B-10-71 | Open-drain driving | | 12.1 | | 8.5 | | 7.3 | | 6.2 | 113 |
| tPLH | Propagation delay time | B-to-A | Push-pull driving | | 10.2 | | 7 | | 5.8 | | 5 ns | |
| u Lii | (low-to-high output) | D-10-71 | Open-drain driving | | 733 | | 578 | | 459 | | | |
| ten | Enable time | OE-to-A or B | Push-pull driving | | 200 | | 200 | | 200 | | 200 | ns |
| tdis | Disable time | OE-to-A or B | Push-pull driving | | 410 | | 410 | | 410 | | 410 | ns |
| trA | Input rise A-po | A-port | Push-pull driving | | 11.9 | | 8.6 | | 7.8 | | 7.2 | ns |
| uz | time | rise time | Open-drain driving | | 996 | | 691 | | 508 | | 350 | 113 |
| trB | Input rise | B-port | Push-pull driving | | 10.5 | | 7.2 | | 5.2 | | 2.7 | ns |
| "" | time | rise time | Open-drain driving | | 1001 | | 677 | | 546 | | 323 | 113 |
| tfA | Input fall | A-port | Push-pull driving | | 8.8 | | 6.6 | | 5.7 | | 4.9 | ns |
| u/A | time | fall time | Open-drain driving | | 9 | | 6.7 | | 5.8 | | 5.2 | 113 |
| tfB | Input fall | B-port | Push-pull driving | | 8.3 | | 5.4 | | 3.9 | | 3 | ns |
| li D | time | fall time | Open-drain driving | | 10.5 | | 10.7 | | 9.6 | | 7.8 | 113 |
| tSK(O) | Skew (time), output | Channel- to- channel skew | Push-pull driving | | 1 | | 1 | | 1 | | 1 | ns |
| Mavim | um data rate | A or B | Push-pull driving | 45 | | 65 | | 70 | | 100 | | NAIs := - |
| iviaxiiII | um uata rate | A or B | Open-drain driving | 0.8 | | 0.8 | | 0.8 | | 1 | | Mbps |



VCCA = 1.8 V over recommended operating free-air temperature range, (unless otherwise noted)

| 545 | | TEST CONDITIONS | | VCCE | 3 = 1.8 V | VCCI | 3 = 2.5 V | VCCI | 3 = 3.3 V | VCCB = 5 V | | UNI |
|-----------|-------------------------|------------------------------------|-----------------------|------|-----------|------|-----------|------|-----------|------------|-----|-----|
| PAF | RAMETER | IESIC | ONDITIONS | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | Т |
| tPHL | Propagation delay time | A-to-B | Push-pull driving | | 8.2 | | 6.4 | | 5.7 | | 5.6 | ns |
| U 11E | (high-to-low output) | A-10-D | Open-drain driving | | 11.4 | | 9.9 | | 9.3 | | 8.9 | 113 |
| tPLH | Propagation delay time | A-to-B | Push-pull driving | | 9 | | 2.1 | | 6.5 | | 6.3 | ns |
| U LII | (low-to-high output) | 710-15 | Open-drain driving | | 729 | | 584 | | 466 | | 346 | 113 |
| tPHL | Propagation delay time | B-to-A | Push-pull driving | | 9.8 | | 8 | | 7.4 | | 7 | ns |
| uii | (high-to-low output) | D-10-A | Open-drain driving | | 12.1 | | 8.5 | | 7.3 | | 6.2 | 113 |
| tPLH | Propagation delay time | B-to-A | Push-pull driving | | 10.2 | | 7 | | 5.8 | | 5 | ne |
| u L11 | (low-to-high output) | D-10-A | Open-drain driving | | 733 | | 578 | | 459 | | 323 | ns |
| ten | Enable time | OE-to-A or B | Push-pull driving | | 200 | | 200 | | 200 | | 200 | ns |
| tdis | Disable time | OE-to-A or B | Push-pull driving | | 400 | | 400 | | 400 | | 400 | ns |
| trA | Input rise | A-port rise | Push-pull driving | | 11.9 | | 8.6 | | 7.8 | | 7.2 | 20 |
| üζ | time | time | Open-drain driving | | 996 | | 691 | | 508 | | 350 | ns |
| trB | Input rise | B-port rise | Push-pull driving | | 10.5 | | 7.2 | | 5.2 | | 2.7 | ns |
| טוי | time | time | Open-drain driving | | 1001 | | 677 | | 546 | | 323 | 113 |
| tfA | Input fall | A-port | Push-pull driving | | 8.8 | | 6.6 | | 5.7 | | 4.9 | ns |
| üΑ | time | fall time | Open-drain driving | | 9 | | 6.7 | | 5.8 | | 5.2 | 115 |
| tfB | Input fall | B-port | Push-pull driving | | 8.3 | | 5.4 | | 3.9 | | 3 | ns |
| ם | time | fall time | Open-drain driving | | 10.5 | | 10.7 | | 9.6 | | 7.8 | 115 |
| tSK(O) | Skew (time), output | Channe I-to- channel skew | Push-pull driving | | 1 | | 1 | | 1 | | 1 | ns |
| Mavim | um data rate | A or B | Push-pull driving | 45 | | 65 | | 110 | | 110 | | Mb |
| IVIANIIII | am data fate | 7010 | Open-drain driving | 0.8 | | 0.8 | | 1.2 | | 1.2 | | ps |



Parameter Measurement Information

Load Circuits

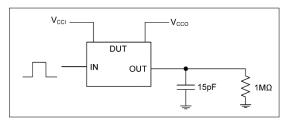


Figure 3 Data Rate, Pulse Duration, Propagation Delay, Output Rise-Time and Fall-Time Measurement Using a Push-Pull Driver

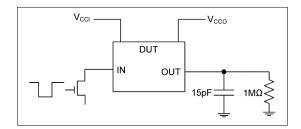
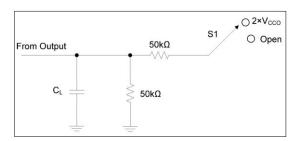


Figure 4 Data Rate, Pulse Duration, Propagation Delay, Output Rise-Time and Fall-Time Measurement Using an Open-Drain Driver



| TEST | S1 |
|-------------|----------|
| tPZL / tPLZ | 2 × VCCO |
| tPHZ / tPZH | Open |

Figure 5 Load Circuit for Enable-Time and Disable-Time Measurement

9

Notes:

- 1. CL includes probe and jig capacitance.
- 2. ten is the same as tPZL and tPZH. tdis is the same as tPLZ and tPHZ.
- 3. VCCI is the supply voltage associated with the input.
- 4. VCCO is the supply voltage associated with the input.

Open-drain and Push-Pull Applications

Voltage Waveforms

The outputs are measured one at a time, with one transition per measurement. All input pulses are supplied by generators that have the following characteristics:

- PRR ≤10 MHz
- $Z_O = 50 \Omega$
- dv/dt ≥1 V/ns

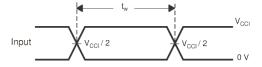


Figure 6 Pulse Duration

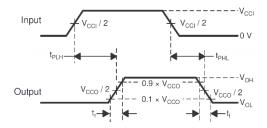
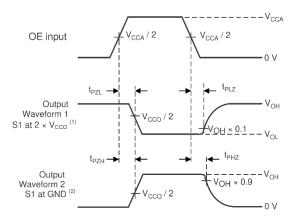


Figure 7 Propagation Delay Times



A. Waveform 1 is for an output with internal such that the output is high, except when OE is high.

B. Waveform 2 is for an output with conditions such that the output is low, except when OE is high.

Figure 8 Enable and Disable Times

Functional Description

Overview

The RS7LS108 device is a directionless voltage-level translator specifically designed for translating logic voltage levels. The A-port accepts I/O voltages ranging from 1.1 V to 1.95 V. The B-port accepts I/O voltages from 1.65 V to 5.5 V. The device uses pass gate architecture with edge rate accelerators (one shots) to improve the overall data rate. The pull-up resistors, commonly used in open-drain applications, have been conveniently integrated so that an external resistor is not needed. While this device is designed for open-drain applications, the device can also translate push-pull CMOS logic outputs.

Each A-port I/O has a pull-up resistor (RPUA) to VCCA and each B-port I/O has a pull-up resistor (RPUB) to VCCB. RPUA and RPUB have a value of 40 k Ω when the output is driving low. RPUA and RPUB have a value of 4 k Ω when the output is driving high. RPUA and RPUB are disabled when OE = Low.

Architecture

Figure 9 describes semi-buffered architecture design this application requires for both push-pull and open- drain mode. This application uses edge-rate accelerator circuitry (for both the high-to-low and low-to-high edges), a high-on-resistance N-channel pass-gate transistor (on the order of 300 Ω to 500 Ω) and pull-up resistors (to provide DC-bias and drive capabilities) to meet these requirements. This design needs no direction- control signal (to control the direction of data flow from A to B or from B to A). The resulting implementation supports both low-speed open-drain operation as well as high-speed push-pull operation.

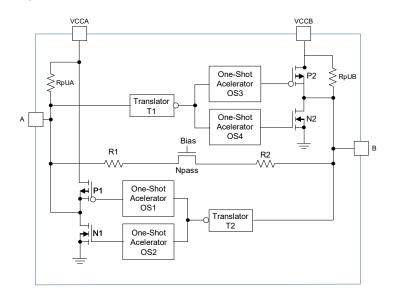


Figure 9. Architecture of a RS7LS108 Cell

When transmitting data from A-ports to B-ports, during a rising edge the one-shot circuit (OS3) turns on the PMOS transistor (P2) for a short-duration which reduces the low-to-high transition time. Similarly, during a falling edge, when transmitting data from A to B, the one-shot circuit (OS4) turns on the N-channel MOSFET transistor (N2) for a short-duration which speeds up the high-to-low transition. The B-port edge-rate accelerator consists of one-shot circuits OS3 and OS4. Transistors P2 and N2 and serves to rapidly force the B port high or low when a corresponding transition is detected on the A port.

When transmitting data from B- to A-ports, during a rising edge the one-shot circuit (OS1) turns on the PMOS transistor (P1) for a short-duration which reduces the low-to-high transition time. Similarly, during a falling edge, when transmitting data from B to A, the one-shot circuit (OS2) turns on NMOS transistor (N1) for a short-duration and these speeds up the high-to-low transition. The A-port edge-rate accelerator consists of one-shots OS1 and OS2, transistors P1 and N1 components and form the edge-rate accelerator and serves to rapidly force the A port high or low when a corresponding transition is detected on the B port.



Bi-directional Level Translator for Open-drain and Push-Pull Applications

Input Driver Requirements

The continuous DC-current sinking capability is determined by the external system-level open-drain (or push-pull) drivers that are interfaced to the RS7LS108 I/O pins. Because the high bandwidth of these bidirectional I/O circuits is used to facilitate this fast change from an input to an output and an output to an input, they have a modest DC-current sourcing capability of hundreds of micro-amperes, as determined by the internal pull-up resistors.

The fall time (tfA, tfB) of a signal depends on the edge-rate and output impedance of the external device driving RS7LS108 data I/Os, as well as the capacitive loading on the data lines.

Similarly, the tPHL and maximum data rates also depend on the output impedance of the external driver. The values for tfA, tfB, tPHL, and maximum data rates in the data sheet assume that the output impedance of the external driver is less than $50~\Omega$.

Output Load Considerations

Raystar recommends careful PCB layout practices with short PCB trace lengths to avoid excessive capacitive loading and to ensure that proper one-shot triggering takes place. PCB signal trace-lengths should be kept short enough such that the round-trip delay of any reflection is less than the one-shot duration. This improves signal integrity by ensuring that any reflection sees a low impedance at the driver. The one-shot circuits have been designed to stay on for approximately 30 ns. The maximum capacitance of the lumped load that can be driven also depends directly on the one-shot duration. With very heavy capacitive loads, the one-shot can time-out before the signal is driven fully to the positive rail. The one-shot duration has been set to best optimize trade-offs between dynamic ICC, load driving capability, and maximum bit-rate considerations. Both PCB trace length and connectors add to the capacitance of the RS7LS108 output. Therefore, Raystar recommends that this lumped-load capacitance is considered in order to avoid one-shot retriggering, bus contention, output signal oscillations, or other adverse system-level affects.

Enable and Disable

The RS7LS108 has an OE pin input that is used to disable the device by setting the OE pin low, which places all I/Os in the Hi-Z state. The disable time (tdis) indicates the delay between the time when the OE pin goes low and when the outputs actually get disabled (Hi-Z). The enable time (ten) indicates the amount of time the design must allow for the one-shot circuitry to become operational after the OE pin goes high.

Pull-up or Pull-down Resistors on I/O Lines

The RS7LS108 has the smart pull-up resistors dynamically change value based on whether a low or a high is being passed through the I/O line. Each A-port I/O has a pull-up resistor (RPUA) to VCCA and each B-port I/O has a pull-up resistor (RPUB) to VCCB. RPUA and RPUB have a value of 40 k Ω when the output is driving low. RPUA and RPUB have a value of 4 k Ω when the output is driving high. RPUA and RPUB are disabled when OE = Low. This feature provides lower static power consumption (when the I/Os are passing a low), and supports lower VOL values for the same size pass-gate transistor, and helps improve simultaneous switching performance.

Device Functional Modes

The RS7LS108 device has two functional modes, enabled and disabled. To disable the device set the OE pin input low, which places all I/Os in a high impedance state. Setting the OE pin input high enables the device.

Application Information

The RS7LS108 can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The device is ideal for use in applications where an open-drain driver is connected to the data I/Os. The device is appropriate for applications where a push-pull driver is connected to the data I/Os, The device is a semi-buffered auto-direction-sensing voltage translator design is optimized for translation applications (for example, MMC Card Interfaces) that require the system to start out in a low-speed open-drain mode and then switch to a higher speed push-pull mode.

Typical Application

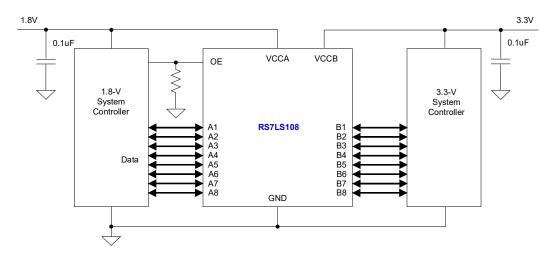


Figure 10 Typical Application Circuit

Design Requirements

To begin the design process, determine the following:

Use the supply voltage of the device that is driving the RS7LS108 device to determine the input and output voltage range. For a valid logic high the value must exceed the VIH of the input port. For a valid logic low the value must be less than the VIL of the input port.

The RS7LS108 device has smart internal pull-up resistors. External pull-up resistors can be added to reduce the total RC of a signal trace if necessary. An external pull-down resistor decreases the output VOH and VOL. Use Equation 1 to calculate the VOH as a result of an external pull-down resistor.

VOH = VCCx × RPD / (RPD + 4
$$k\Omega$$
)

Power Supply Recommendations

During operation, ensure that VCCA ≤ VCCB at all times. The sequencing of each power supply will not damage the device during the power up operation, so either power supply can be ramped up first. The output-enable (OE) input circuit is designed so that it is supplied by VCCA and when the (OE) input is low, all outputs are placed in the high-impedance state. To ensure the high-impedance state of the outputs during power up or power down, the OE input pin must be tied to GND through a pull-down resistor and must not be enabled until VCCA and VCCB are fully ramped and stable. The minimum value of the pull-down resistor to ground is determined by the current-sourcing capability of the driver.

Layout Guidelines

To ensure reliability of the device, following common printed-circuit board layout guidelines is recommended.

Bypass capacitors should be used on power supplies. Place the capacitors as close as possible to the VCCA, VCCB pin and GND pin.

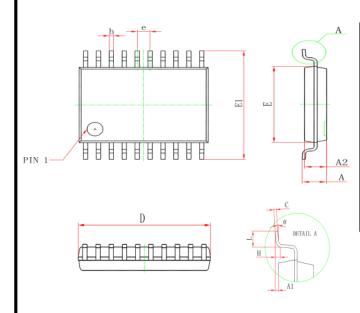
Short trace lengths should be used to avoid excessive loading.

PCB signal trace-lengths must be kept short enough so that the round-trip delay of any reflection is less than the one-shot duration, approximately 30 ns, ensuring that any reflection encounters low impedance at the source driver.



Package Information

TSSOP20



| Symbol | Dimensions In | Millimeters | Dimensions In Inches | | | |
|--------|---------------|-------------|----------------------|--------|--|--|
| Symbol | Min | Max | Min | Max | | |
| D | 6. 400 | 6.600 | 0.252 | 0.259 | | |
| Е | 4. 300 | 4.500 | 0.169 | 0.177 | | |
| b | 0.190 | 0.300 | 0.007 | 0.012 | | |
| с | 0.090 | 0. 200 | 0.004 | 0.008 | | |
| E1 | 6. 250 | 6. 550 | 0.246 | 0. 258 | | |
| A | | 1. 200 | | 0.047 | | |
| A2 | 0.800 | 1.000 | 0.031 | 0.039 | | |
| A1 | 0.050 | 0.150 | 0.002 | 0.006 | | |
| e | 0.65 | BSC) | 0.026 | (BSC) | | |
| L | 0.500 | 0.700 | 0.020 | 0.028 | | |
| Н | 0.25(1 | YP) | 0.01(TYP) | | | |
| θ 1° | | 7° | 1° | 7° | | |

Note:

- 1. All dimensions are in mm. Angels in degrees.
- 2. Dimensions exclude burrs, mold flash or protrusions.
- 3. Refer Jedec MS-012

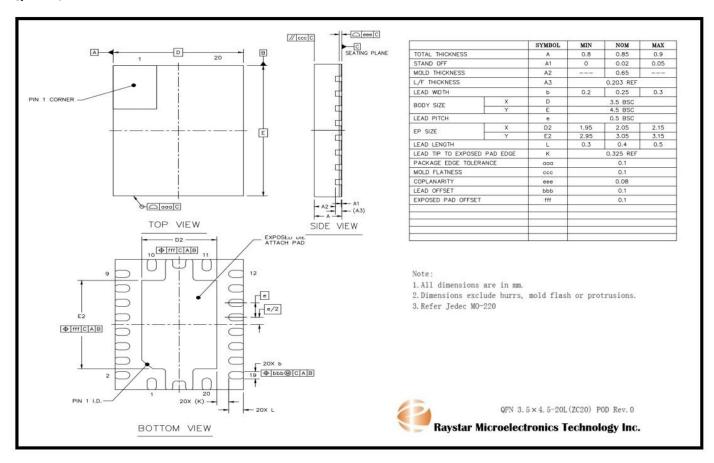


TSSOP20(173mil) POD Rev. 0

Raystar Microelectronics Technology Inc.



QFN-20



RS7LS108

Bi-directional Level Translator for Open-drain and Push-Pull Applications

Revision History

| Revision | Description | DATE |
|----------|-------------------------------------------|-----------|
| 1.0 | Initial release | 2024/11/6 |
| 1.1 | Update OE maximum voltage | 2025/3/19 |
| 1.2 | Update AC Electrical characteristics spec | 2025/6/23 |